

ST3222

3 TO 3.6V, LOW POWER, UP TO 400KBPS, RS-232 DRIVERS AND RECEIVERS

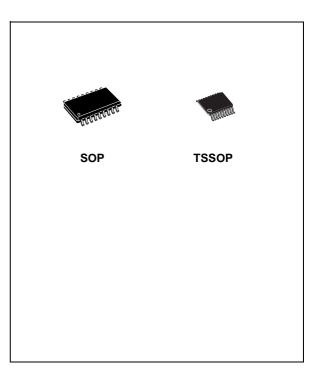
- 300µA SUPPLY CURRENT
- 250Kbps MINIMUM GUARENTEED DATA RATE
- 6V/µs MINIMUM GUARANTEED SLEW RATE
- MEET EIA/TIA-232 SPECIFICATIONS DOWN TO 3V
- AVAILABLE IN SO-18 AND TSSOP20

DESCRIPTION

The ST3222 is a 3V powered EIA/TIA-232 and V.28/V.24 communications interface with low power requirements and high data-rate capabilities. ST3222 has a proprietary low dropout transmitter output stage providing true RS-232 performance from 3 to 3.6V power supplies. The device requires only four small $0.1\mu F$ standard external capacitors for operating from 3V supply.

The ST3222 has two receivers and two drivers. The ST3222 features a $1\mu A$ shutdown mode that reduces power consumption and extends battery life in portable systems. Its receivers can remain active in shutdown mode, allowing external devices such as modems to be monitored using only $1\mu A$ supply current.

The device is guaranteed to run at data rates of 250Kbps while maintaining RS-232 output levels.



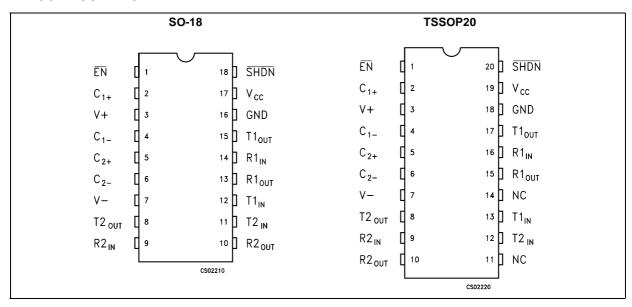
Typical applications are Notebook, Subnotebook and Palmtop Computers, Battery Powered Equipment, Hand-Held Equipment, Peripherals and Printers.

ORDERING CODES

| Туре | Temperature Range | Package | Comments |
|-----------|----------------------|-----------------------|-----------------------------------|
| ST3222CD | 0 to 70 °C | SO-18 (Tube) | 50parts per tube / 20tube per box |
| ST3222BD | -40 to 85 °C | SO-18 (Tube) | 50parts per tube / 20tube per box |
| ST3222CDR | 0 to 70 °C | SO-18 (Tape & Reel) | 1000 parts per reel |
| ST3222BDR | -40 to 85 °C | SO-18 (Tape & Reel) | 1000 parts per reel |
| ST3222CTR | 0 to 70 °C | TSSOP20 (Tape & Reel) | 2500 parts per reel |
| ST3222BTR | -40 to 85 °C | TSSOP20 (Tape & Reel) | 2500 parts per reel |

October 2002 1/9

PIN CONFIGURATION



PIN DESCRIPTION

| PIN N° (SO-18) | PIN N° (TSSP20) | SYMBOL | NAME AND FUNCTION |
|----------------|-----------------|-------------------|---|
| 1 | 1 | EN | Receiver Enable Control. Drive low for normal operation. Drive high to force the receivers outputs (R_OUT) into a high-impedance state. |
| 2 | 2 | C ₁ + | Positive Terminal for the first Charge Pump Capacitor |
| 3 | 3 | V+ | 5.5V Generated By The Charge Pump. |
| 4 | 4 | C ₁ - | Negative Terminal for the first Charge Pump Capacitor |
| 5 | 5 | C ₂ + | Positive Terminal for the second Charge Pump Capacitor |
| 6 | 6 | C ₂ - | Negative Terminal for the second Charge Pump Capacitor |
| 7 | 7 | V- | -5.5V Generated By The Charge Pump. |
| 8 | 8 | T2 _{OUT} | Second Transmitter Output Voltage |
| 9 | 9 | R2 _{IN} | Second Receiver Input Voltage |
| 10 | 10 | R2 _{OUT} | Second Receiver Output Voltage |
| | 11 | NC | Not Connected |
| 11 | 12 | T2 _{IN} | Second Transmitter Input Voltage |
| 12 | 13 | T1 _{IN} | First Transmitter Input Voltage |
| | 14 | NC | Not Connected |
| 13 | 15 | R1 _{OUT} | First Receiver Output Voltage |
| 14 | 16 | R1 _{IN} | First Receiver Input Voltage |
| 15 | 17 | T1 _{OUT} | First Transmitter Output Voltage |
| 16 | 18 | GND | Ground |
| 17 | 19 | V _{CC} | Supply Voltage |
| 18 | 20 | SHDN | Active Low Shutdown Control Input. Drive Low To Shut-down Trnasmittes And Charge Pump |

▲7/

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|--------------------|--------------------------------------|---------------------------------|------|
| V _{CC} | Supply Voltage | -0.3 to 6 | V |
| V+ | Doubled Voltage Terminal | (V _{CC} - 0.3) to 7 | V |
| V- | Inverted Voltage Terminal | 0.3 to -7 | V |
| V+ + V- | | 13 | V |
| T _{IN} | Transmitter Input Voltage Range | -0.3 to 6 | V |
| SHDN | Transmitter Input Voltage Range | -0.3 to 6 | V |
| R _{IN} | Receiver Input Voltage Range | ± 25 | V |
| T _{OUT} | Transmitter Output Voltage Range | ± 13.2 | V |
| R _{OUT} | Receiver Output Voltage Range | -0.3 to (V _{CC} + 0.3) | V |
| t _{SHORT} | Transmitter Output Short to GND Time | Continuous | |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied. V+ and V- can have a maximum magnitude of +7V, but their absolute addition can not exceed 13 V.

ELECTRICAL CHARACTERISTICS

(C₁ - C₄ = 0.1 μ F, V_{CC} = 3V to 3.6V, T_A = -40 to 85°C, unless otherwise specified. Typical values are referred to T_A = 25°C)

| Symbol | Parameter | Test Conditions | Min. | Тур. | Max. | Unit |
|---------------------|--------------------------------------|---------------------------------------|------|------|------|------|
| I _{SUPPLY} | V _{CC} Power Supply Current | No Load $V_{CC} = 3.3V$ $T_A = 25$ °C | | 0.3 | 1 | mA |
| | | SHDN=V _{CC} | | | | |
| 0 | SHUTDOWN Supply | No Load $V_{CC} = 3.3V$ $T_A = 25$ °C | | 1 | 10 | μΑ |
| | Current | SHDN=V _{CC} | | | | |

LOGIC INPUT ELECTRICAL CHARACTERISTICS

 $(C_1$ - C_4 = 0.1 $\mu F,~V_{CC}$ = 3V to 3.6V, T_A = -40 to 85°C, unless otherwise specified. Typical values are referred to T_A = 25°C)

| Symbol | Parameter | Test Conditions | Min. | Тур. | Max. | Unit |
|------------------|---------------------------------|-------------------------|------|--------|------|------|
| V _{IL} | Input Logic Threshold Low | T-IN, EN, SHDN (Note 1) | | | 0.8 | V |
| V _{IH} | Input Logic Threshold High | V _{CC} = 3.3V | 2 | | | V |
| V _{HYS} | Transmitter Input Histeresys | | | 0.5 | | V |
| I _{IL} | Input Leakage Current | T-IN, EN, SHDN | | ± 0.01 | ± 1 | μΑ |

Note 1: Transmitter input hysteresis is typically 250mV

TRANSMITTER ELECTRICAL CHARACTERISTICS

(C₁ - C₄ = $0.1\mu F$ V_{CC} = 3V to 3.6V, T_A = -40 to 85°C, unless otherwise specified. Typical values are referred to T_A = 25°C)

| Symbol | Parameter | Test Condit | Min. | Тур. | Max. | Unit | |
|-------------------|-------------------------------|--|---------------------|------|-------|------|----|
| V _{TOUT} | Output Voltage Swing | All Transmitter outputs at $3K\Omega$ to GND | re loaded with | ± 5 | ± 5.4 | | V |
| R _{TOUT} | Transmitter Output Resistance | $V_{CC} = V + = V - = 0V$ | $V_{OUT} = \pm 2V$ | 300 | 10M | | Ω |
| I _{TSC} | Output Short Circuit Current | | | | | ± 60 | mA |
| I _{TOL} | Output Leakage Current | V _{CC} = 0V or 3V to 3.6V Transmitters Disable | $V_{OUT} = \pm 12V$ | | | ± 25 | μΑ |

RECEIVER ELECTRICAL CHARACTERISTICS

(C₁ - C₄ = 0.1 μ F V_{CC} = 3V to 3.6V, T_A = -40 to 85°C, unless otherwise specified. Typical values are referred to T_A = 25°C)

| Symbol | Parameter | Test Conditions | Min. | Тур. | Max. | Unit |
|--------------------|---|---|----------------------|----------------------|------|------|
| I _{OL} | Output Leakage Current | R-OUT, $\overline{EN} = V_{CC}$, Receiver Disabled | | ± 0.05 | ± 10 | μΑ |
| V _{RIN} | Receiver Input Voltage Operating Range | | -25 | | 25 | V |
| V _{RIL} | Input Threshold Low | $T_A = 25$ °C $V_{CC} = 3.3$ V | 0.6 | 1.2 | | V |
| V _{RIH} | Input Threshold High | $T_A = 25^{\circ}C$ $V_{CC} = 3.3V$ | | 1.5 | 2.4 | V |
| V _{RIHYS} | Input Hysteresis | | | 0.5 | | V |
| R _{RIN} | Input Resistance | T _A = 25°C | 3 | 5 | 7 | ΚΩ |
| V _{ROL} | TTL/CMOS Output Voltage Low | I _{OUT} = 1.6mA | | | 0.4 | V |
| V _{ROH} | TTL/CMOS Output Voltage High | I _{OUT} = -1mA | V _{CC} -0.6 | V _{CC} -0.1 | | V |

TIMING CHARACTERISTICS

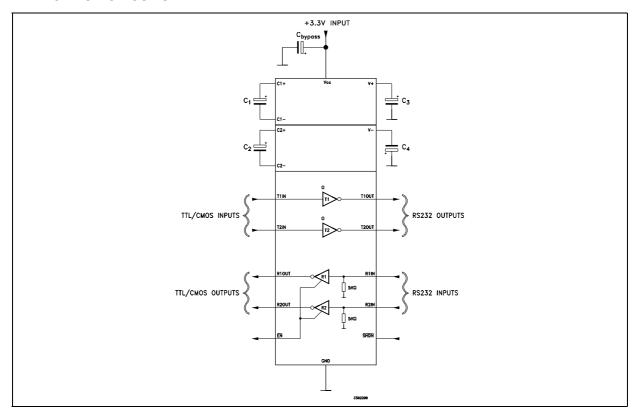
(C₁ - C₄ = 0.1 μ F, V_{CC} = 3V to 3.6V, T_A = -40 to 85°C, unless otherwise specified. Typical values are referred to T_A = 25°C)

| Symbol | Parameter | Test Conditions | Min. | Тур. | Max. | Unit |
|---|--|--|--------|------|----------|--------------|
| D _R | Data Transfer Rate | $R_L = 3K\Omega$ $C_{L2} = 1000pF$ one trasmitter switching | 240 | 400 | | Kbps |
| t _{PHLR} t _{PLHR} | Propagation Delay Input to Output | R_{XIN} to R_{XOUT} $C_L = 150pF$ | | 0.2 | | μs |
| t _{PHLT} - t _{THL} | Transmitter Propagation Delay Difference | (Note 1) | | 100 | | ns |
| toer | Receiver Output Enable Time | Normal Operation | | 200 | | ns |
| t _{ODR} | Receiver Output Disable Time | Normal Operation | | 200 | | ns |
| t _{PHLR} - t _{THR} | Receiver Propagation Delay Difference | | | 50 | | ns |
| S _{RT} | Trnasition Slew Rate | $T_A = 25^{\circ}C$ $R_L = 3K\Omega$ to $7K\Omega$ $V_{CC} = 3.3V$ | | | | |
| | | measured from +3V to -3V or -3V to +3V $C_L = 150 pF$ to $1000 pF$ $C_L = 150 pF$ to $2500 pF$ | 6 4 | | 30 30 | V/μs V/μs |

Transmitter Skew is measured at the transmitter zero cross points

4/9

APPLICATION CIRCUITS



CAPACITANCE VALUE (µF)

| C1 | C2. | C 3 | C4 | Cbypass |
|-----|-----|------------|-----|---------|
| 0.1 | 0.1 | 0.1 | 0.1 | 0.1 |

TYPICAL PERFORMANCE CHARACTERISTICS (unless otherwise specified $T_i = 25$ °C)

Figure 1 : Driver Voltage Transfer Characteristics for Trasmitter Inputs

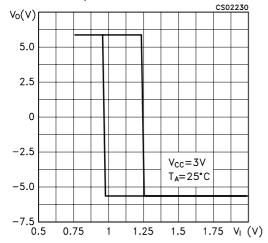


Figure 2 : Driver Voltage Transfer Characteristics for Receiver Inputs

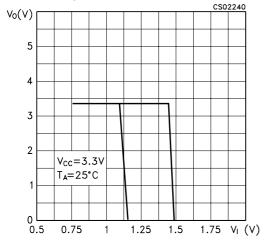


Figure 3: Output Current vs Output Low Voltage

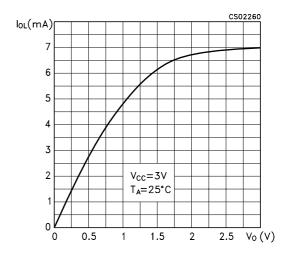
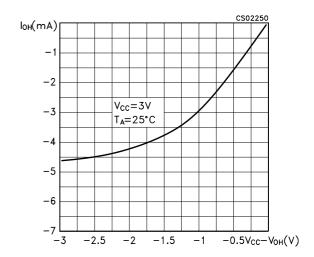


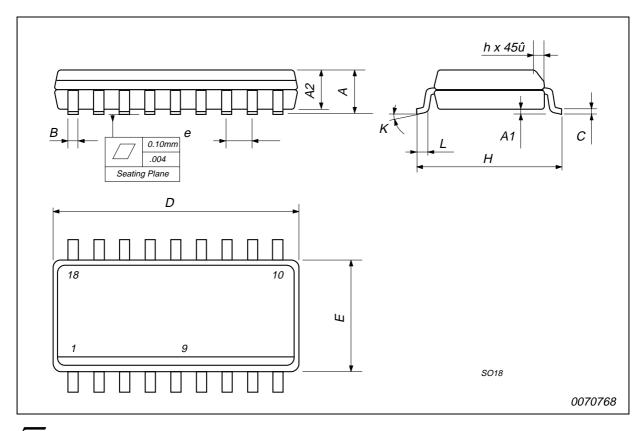
Figure 4 : Output Current vs Output High Voltage



6/9

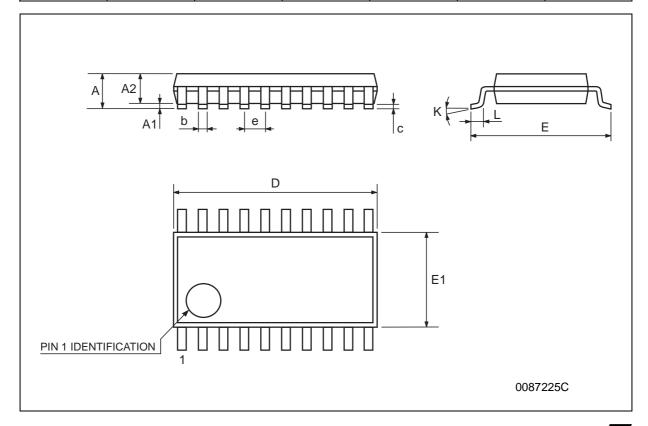
SO-18 MECHANICAL DATA

| DIM | | mm. | | | inch | | | |
|------|-------|------|-------|-------|-------|-------|--|--|
| DIM. | MIN. | TYP | MAX. | MIN. | TYP. | MAX. | | |
| Α | 2.35 | | 2.65 | 0.092 | | 0.104 | | |
| A1 | 0.1 | | 0.3 | 0.004 | | 0.012 | | |
| A2 | | | 2.55 | | | 0.100 | | |
| В | 0.33 | | 0.51 | 0.013 | | 0.020 | | |
| С | 0.23 | | 0.32 | 0.009 | | 0.012 | | |
| D | 11.35 | | 11.75 | 0.447 | | 0.462 | | |
| E | 7.4 | | 7.6 | 0.291 | | 0.299 | | |
| е | | 1.27 | | | 0.050 | | | |
| Н | 10.00 | | 10.65 | 0.393 | | 0.419 | | |
| h | 0.25 | | 0.75 | 0.010 | | 0.029 | | |
| k | 8 | | ° (r | max.) | | • | | |
| L | 0.4 | | 1.27 | 0.016 | | 0.050 | | |



TSSOP20 MECHANICAL DATA

| DIM. | | mm. | | | inch | | | |
|------|------|----------|------|-------|------------|--------|--|--|
| | MIN. | TYP | MAX. | MIN. | TYP. | MAX. | | |
| А | | | 1.2 | | | 0.047 | | |
| A1 | 0.05 | | 0.15 | 0.002 | 0.004 | 0.006 | | |
| A2 | 0.8 | 1 | 1.05 | 0.031 | 0.039 | 0.041 | | |
| b | 0.19 | | 0.30 | 0.007 | | 0.012 | | |
| С | 0.09 | | 0.20 | 0.004 | | 0.0079 | | |
| D | 6.4 | 6.5 | 6.6 | 0.252 | 0.256 | 0.260 | | |
| E | 6.2 | 6.4 | 6.6 | 0.244 | 0.252 | 0.260 | | |
| E1 | 4.3 | 4.4 | 4.48 | 0.169 | 0.173 | 0.176 | | |
| е | | 0.65 BSC | | | 0.0256 BSC | | | |
| К | O° | | 8° | 0° | | 8° | | |
| L | 0.45 | 0.60 | 0.75 | 0.018 | 0.024 | 0.030 | | |



8/9

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

© The ST logo is a registered trademark of STMicroelectronics

© 2002 STMicroelectronics - Printed in Italy - All Rights Reserved STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco Singapore - Spain - Sweden - Switzerland - United Kingdom - United States.

© http://www.st.com

